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Phys. Rev. Lett. 119, 053402 — Published 1 August 2017
DOI: 10.1103/PhysRevLett.119.053402
Direct Observation and Characterization of Neutral Radicals from a Dissociative Electron Attachment Process

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Despite decades of gas-phase studies on dissociative electron attachment (DEA) to various molecules, as yet there has been no direct detection and characterization of the neutral radical species produced by this process. In this study, we performed stepwise electron spectroscopy (SWES) to directly measure and characterize the neutrals produced upon zero-electron-energy DEA to the model molecule, carbon tetrachloride (CCl4). We observed the direct yield of the trichloromethyl radical (CCl3•) formed by DEA to CCl4 and measured the appearance energies of all the other neutral species. By combining these experimental findings with high-level quantum chemical calculations, we performed a complete analysis of both the DEA to CCl4 and the subsequent electron-impact ionization of CCl3•. This work paves the way toward a complete experimental characterization of DEA processes, which will lead to a better understanding of the low-energy electron-induced formation of radical species.

Low-energy electrons (< 15 eV) can resonantly attach to molecules to form a short-lived transient state that quickly decays through molecular dissociation into a negative ion and neutral (radical) fragment(s). This process, commonly known as dissociative electron attachment (DEA), appears to have great significance in nature and technology, and has attracted a huge amount of scientific attention in recent decades. DEA represents a doorway for sub-ionization and even sub-excitation energy electrons to induce the decomposition of complex molecular species. Consequently, DEA studies are shedding new light on important research topics, such as radiation damage [1], and on the development of industrial applications, such as high-resolution nanolithography [2,3]. In addition, DEA is also a doorway for low-energy electrons to produce highly reactive radical species, which, themselves, play a crucial role in a variety of important biological and industrial processes. Nevertheless, despite intensive gas-phase DEA research, there has been no report of the direct detection and characterization of neutral radicals produced in DEA performed under well-defined single-collision conditions.

DEA to carbon tetrachloride (CCl4) represents one of the most studied of these processes. At incident electron energies close to 0 eV, DEA to CCl4 leads to the formation of only Cl– ions [4], while the other reaction product is surmised to be the trichloromethyl radical (CCl3–):

\[ e^{-}(E) + \text{CCl}_{4} \rightarrow \text{CCl}_{4}^{*} \rightarrow \text{Cl}^{-} + \text{CCl}_{3}^{•} \]  

(1)

The intermediate anion CCl4* quickly dissociates within 5–10 ps [5]. The resonant Reaction (1) attains a maximum at 0 eV with a large DEA cross section (1.3×10^{-14} cm^2 [6]), and thus represents a convenient process for our experimental investigation on the direct yield of neutral species. Moreover, CCl3• radicals can be efficiently produced by Reaction (1) even from, e.g., presolvated electrons [7], enzymes acting as electron donors in electron transfer reactions [8], thermal electrons in plasma [9], and photoelectrons produced on surfaces (both below and above vacuum level) [10]. Therefore, Reaction (1) is involved (or considered to be involved) in a number of important processes that span many distinct fields from Earth’s atmospheric processes [11], to plasma applications [12,13], surface photochemistry [10,14], and toxicology [8,15,16].

To directly measure the yield of CCl3• radicals as a function of the electron energy E upon DEA to CCl4 (1), we performed stepwise electron spectroscopy (SWES) of gaseous CCl4. The main rationale for using this technique was to detect neutral radical species formed through DEA by using electron impact ionization subsequent to the DEA process (see Fig. 1). In each step, we chose the desired combination of electron interaction time, ion acquisition time, and impact electron energy. Moreover, we also chose the step in which to acquire the selected ionic species.

Therefore, for each type of measurement we designed an acquisition algorithm, which we executed for the desired number of cycles, to provide data streaming from which we ultimately extracted the yield (counts per second) of the desired ionic species (m/z) acquired during a given step, and as a function of the electron energy in the first step (E1).
between \( \text{CCl}_4 \) and \( \text{CCl}_3 \) assumption of both a large difference in the target density region during a time interval (Fig. 1(b)), where, in the first step, electrons at energy \( E_1 \) interacted with molecules in the collision region during the time \( t_1 = 0.1 \text{s} \). The \( t_1 \) and \( t_2 \) were adjusted taken into account several technical considerations, such as degradation of a filament, working at \( \sim 0 \text{ eV} \) and at high electron emission, \( \text{CCl}_1^+ \) quenching time, time limitation needed to achieve a sufficient electron emission, and an optimal signal to noise ratio. We acquired the positive ions \( \text{CCl}_1^+ \) during this second step, \( t_2 \). Note that \( \text{CCl}_1^+ \) can be produced by both the electron impact fragmentation (EIF) of \( \text{CCl}_4 \) molecules (in the target beam) and the electron impact ionization (EI) of the \( \text{CCl}_1 \) radical formed in Reaction (1) during time \( t_1 \). However, if the 2\textsuperscript{nd}-step electron energy \( E_2 \) is close to the ionization energy (IE) of \( \text{CCl}_1^+ \) and lower than the appearance energy (AE) of \( \text{CCl}_1^+ \) from EIF of \( \text{CCl}_4 \), this acquisition scheme allows only for the detection of the \( \text{CCl}_1^+ \) species produced in Reaction (1). Therefore, by repeating this acquisition scheme at different energies \( E_i \), we measured the yield of \( \text{CCl}_1^+ \) from Reaction (1) as a function of the incident electron energy scanned over the DEA resonance. Since both Cl\(^-\) and \( \text{CCl}_1^+ \) are formed in the same reaction, the relative ion yields obtained from the 1\textsuperscript{st}- and 2\textsuperscript{nd}-step acquisition schemes should overlap. This is indeed shown in Fig. 2(a), in which the red circles represent the yield of \( \text{CCl}_1^+ \) for \( E_2 = 11 \text{ eV} \). Note that we normalized the significantly lower intensity \( \text{CCl}_1^- \) curve to that of \( \text{Cl}^- \) and we calibrated the energy scale according to the decreasing slope of the \( \text{Cl}^- \) curve. To the best of our knowledge, this is the first direct measurement of the resonant yield of neutral species formed by gas-phase DEA.

For example, in the 1\textsuperscript{st} step of the acquisition scheme (see Fig. 1(b)), the electrons at energy \( E_1 \) interacted with molecules in the collision region during time \( t_1 \), and Cl\(^-\) ions (formed by DEA to \( \text{CCl}_4 \)) were acquired during the same time window \( t_1 \). Therefore, by repeating this acquisition scheme at different energies \( E_i \), we measured the yield of \( \text{Cl}^- \) as a function of the incident electron energy \( E_i \), which represents a classical DEA experiment. The blue curve in Figure 2(a) presents the results, which shows the well-known resonance feature corresponding to the 0-eV DEA to \( \text{CCl}_4 \), although it is somewhat broadened due to our lower energy resolution. It is worth noting that a secondary DEA process: \( e^- + \text{CCl}_3 \rightarrow \text{Cl}^- + \text{CCl}_2 \) is also possible [9] during interaction time \( t_i \) and also is computed to be exothermic. Nevertheless, we consider that contribution of \( \text{Cl}^- \) from the secondary DEA to be negligible, based on the assumption of both a large difference in the target density between \( \text{CCl}_4 \) and \( \text{CCl}_1^+ \) and a very low probability of the occurrence of this two-step process under single-collision conditions.

Furthermore, we performed the 2-step acquisition scheme (Fig. 1(b)), where, in the first step, electrons at energy \( E_1 \) interacted with molecules in the collision region during the time \( t_1 = 1 \text{s} \), followed by a second step, in which electrons at energy \( E_2 \) interacted with molecules in the collision region during a time interval \( t_2 = 0.1 \text{s} \). The \( t_1 \) and \( t_2 \) were adjusted taken into account several technical considerations.
impact ionization yield of CCl$_3^+$ for $E_2$ between 6 and 11 eV (red squares), for which we estimated the yield as the total CCl$_3$ yield for $E_1$ at 0 - 4.5 eV, i.e., the area under the red curve in Fig. 2(a). For comparison, in Fig. 2(b) we plotted the yield of CCl$_3^+$ formed by the electron impact dissociation of neutral CCl$_4$ measured in the 1$^{st}$-step acquisition scheme under the same experimental conditions (blue dots). Based on a Wannier fit [18] to the experimental data obtained in the 2$^{nd}$-step acquisition (Fig. 2(b), red curve), we determined the IE of CCl$_3^+$ to be at 8.1 ± 0.5 eV. This value closely matches previously reported experimentally-determined values of 8.11 eV [19] and 8.06 eV [20]. The uncertainty of the present IE is due to a low signal to noise ratio at the threshold and limited electron resolution. The calculated adiabatic IE of CCl$_3^+$ has been reported to be 7.954 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV and an adiabatic IE of 8.02 eV. Note that a distinct Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20]. Our calculations performed at the ccsd(t)/aug-cc-pVTZ level [21–24] with the Gaussian09 [25] package resulted in a vertical IE of 8.70 eV [20].

We note that CCl$_3^+$ is formed only in the first-step process through Reaction (1), because for our calculations (again at the ccsd(t)/aug-cc-pVTZ level), the formation of CCl$_3^+$ from the direct C–Cl bond cleavage in CCl$_4$, CCl$_4$ → CCl$_3^+$ + Cl, requires an energy not less than 2.9 eV and the yield of CCl$_3^+$ seen in Fig. 2(a) appears mostly in the region $E_1<1$ eV. Consequently, the density of CCl$_3^+$ in the collision region should decrease in time after the completion of the first step. This was probed by the multistep SWES measurements. Figure 2(c) shows the time dependence of CCl$_3$ abundance, in which, after the first step in the DEA process, we set the electron energy at $E_2=15$ eV and recorded the intensity of CCl$_3^+$ as output every 10 ms. Note that $E_2$ was above CCl$_3^+$/CCl$_4$ AE (Fig. 2b) to ensure high enough CCl$_3$ detection efficiency during a short acquisition time of secondary steps. However, CCl$_3^+$ produced directly from CCl$_4$ made a constant background which was subtracted. The quenching of CCl$_3$ is a consequence of several processes, which cannot be resolved in the present experiment. These processes include electron interaction (ionization and fragmentation); CCl$_3^+$ interaction with the target beam, the residual gas molecules, and surrounding surfaces; and the escape of neutral radicals due to their translational kinetic energy.

In addition to the resonant yield of the CCl$_3$ radical observed from DEA to CCl$_4$ (Fig. 2(a)), we also detected all the other positive ions that can possibly originate as neutrals from CCl$_4$ fragmentation. The gas-phase DEA to CCl$_4$ at incident electron energies close to 0 eV can proceed only by Reaction (1). We probed the origin of these smaller ionic fragments by determining their AE as a function of the second-step energy $E_2$ (Figure 3). The measured yields of CCl$_3^+$ and CCl$_4^+$ cationic fragments demonstrate that their appearance thresholds fall between the IE of the corresponding neutrals and their AE from CCl$_4$ dissociative ionization (Figs. 3(a) and 3(b)). Therefore, these fragments can only appear from the electron impact dissociative ionization of CCl$_3^+$ formed in the DEA to CCl$_4$, which offers the first opportunity to measure AEs of these fragments from the CCl$_3$ radical. Notably, the formation of Cl$_2^+$ and Cl$_2^+$ occurred close to energies of the IEs of their neutrals (Figs. 3(c) and 3(d)), therefore these two cations result from the ionization of Cl$^+$ and Cl$_2^+$ rather than the EIF of CCl$_3$ or CCl$_4$. This is in accordance with the present calculations (Table I) showing that their AEs lay far above experimentally-probed electron energy domain.

Note: dashed lines represent experimentally-determined IEs and AEs, as reported in given references.

Considering electron interaction with radicals in the gas phase, to our knowledge, only those with fluorocarbon radicals have been investigated to date, including measurements of absolute elastic cross sections for CF$_2$ and...
CF$_3$ [26,27] and DEA processes for CF$_2$ and C$_2$F$_5$ [28,29]. In the latter experiments, the target radical beam has been obtained by pyrolysis or microwave discharge. With respect to the CCl$_3$ radical, the only relevant study was reported by Adams et al. [9], who used a flowing afterglow/Langmuir probe apparatus to measure a rate coefficient for a secondary process of DEA to CCl$_4^*$ formed in the primary DEA to CCl$_4$. Also, the CCl$_3$ radical has been studied, both theoretically and experimentally, using mass spectrometry, laser spectroscopy, and ab initio calculations [20,30–32]. From these calculations, electron impact IE and photon impact IE for CCl$_3^*$ were reported previously, but no data on the EIF of CCl$_3$ excited state. To estimate the effect of temperature, enthalpy requirement by less than 0.2 eV, which could not explain the deviation observed in the experiment. Thus, it is more plausible the deviation is owing to an initial excited CCl$_3^*$ and CCl$_3^+$, respectively. The deviation between the measurement and the calculation might be explained by two reasons: the region close to the filament where the reactions occurred can be of very high temperature and the parent molecule CCl$_3^*$ resulting from the first-step DEA might be in an excited state. To estimate the effect of temperature, enthalpy changes for different pathways were calculated at various temperatures with complete basis set method CBS-QB3 [33,34] as listed in Table I. The increase in temperature from 300 to 2500 K lowers the enthalpy requirement by less than 0.2 eV, which could not explain the deviation observed in the experiment. Thus, it is more plausible the deviation is owing to an initial excited CCl$_3^*$ state. Previously, Popple et al. [5] reported the excess energy of Reaction (1) to be ~0.61 eV and concluded that there is an efficient redistribution of this excess reaction energy among the internal vibrational modes of the intermediate CCl$_3^*$ prior to dissociation, leaving only about 0.1 eV as a mean translational energy release.

Our calculations (at the ccsv/(t)/aug-cc-pVTZ level) predicted the AEs of CCl$_2^*$ and CCI$^+$ from CCl$_4^*$ at 12.01 and 12.51 eV, respectively. These energies are about 1.5 eV above the experimentally measured thresholds of 10.55 ± 0.5 and 10.49 ± 0.5 eV for CCl$_2^*$ and CCl$^+$, respectively. The deviation between the measurement and the calculation might be explained by two reasons: the region close to the filament where the reactions occurred can be of very high temperature and the parent molecule CCl$_3^*$ resulting from the first-step DEA might be in an excited state. To estimate the effect of temperature, enthalpy changes for different pathways were calculated at various temperatures with complete basis set method CBS-QB3 [33,34] as listed in Table I. The increase in temperature from 300 to 2500 K lowers the enthalpy requirement by less than 0.2 eV, which could not explain the deviation observed in the experiment. Thus, it is more plausible the deviation is owing to an initial excited CCl$_3^*$ state. Previously, Popple et al. [5] reported the excess energy of Reaction (1) to be ~0.61 eV and concluded that there is an efficient redistribution of this excess reaction energy among the internal vibrational modes of the intermediate CCl$_3^*$ prior to dissociation, leaving only about 0.1 eV as a mean translational energy release.

TABLE I. Enthalpies calculated with CBS-QB3 method at 300 K and 2500 K for different reaction pathways.

<table>
<thead>
<tr>
<th>M$^+$</th>
<th>$\Delta H$ M $\rightarrow$ M$^*$ + e$^-$</th>
<th>$\Delta H$ CCl$_3^<em>$ $\rightarrow$ M$^</em>$ + B + e$^-$</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>300 K</td>
<td>2500 K</td>
</tr>
<tr>
<td>CCl$_4^*$</td>
<td>9.28</td>
<td>9.21</td>
</tr>
<tr>
<td>CCl$^+$</td>
<td>8.78</td>
<td>8.77</td>
</tr>
<tr>
<td>Cl$^+$</td>
<td>12.92</td>
<td>12.92</td>
</tr>
<tr>
<td>Cl$_2^+$</td>
<td>11.53</td>
<td>11.53</td>
</tr>
</tbody>
</table>

In conclusion, we designed a SWES method to probe the CCl$_3$ radicals resulting from gas-phase DEA to CCl$_4$ around zero eV. With this scheme, we measured the IE of CCl$_3^*$ as well as the lifetime of CCl$_3^*$ in vacuum conditions. We examined the cationic fragments resulted from EIF of CCl$_3^*$ by measuring the ion yield curves of the cation fragments as a function of electron energy. By comparing the AEs and the calculated thresholds of different reaction pathways, we determined the AEs for CCl$_2^*$ and CCI$^+$ formed by the EIF of CCl$_3^*$. The great advantage of this SWES methodology is that the production of the radicals and the subsequent ionization of the radicals can be performed in the same reaction compartment. In this way, we overcame the challenge of radical decay during transportation from the production site to the ionization site as reported in some other radical detection methods [35,36]. The method described here will have useful application in the investigation of radicals from the gas phase DEA, for which no studies have been reported. Obtaining a comprehensive picture of DEA processes has the potential to transform our understanding of the interactions of low-energy electrons with molecular systems, yielding basic science information which translates on variety biological and industrial applications.

Acknowledgement

This material is based upon work supported by the U.S. Department of Energy Office of Science, Office of Basic Energy Sciences under Award Number DE-FC02-04ER15533. This is contribution number NDRL 5161 from the Notre Dame Radiation Laboratory.


